



Physics and chemistry of nanostructures

Progress Navolchi project

March 12th, 2012

Prof. Zeger Hens Ghent University Belgium







Outline

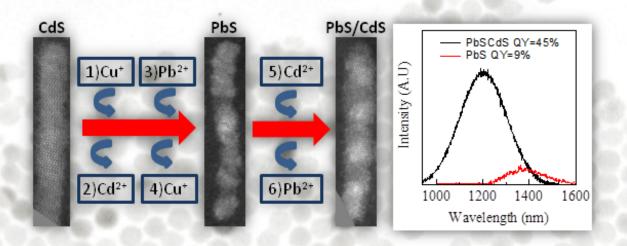
- Materials
 - PbX/CdX heterostructures
- Processing
- Properties
 - Absorption enhancement in QD monolayers
 - Intraband absorption with PbX QDs
 - Pump-probe measurements -> amplification
- Devices
 - Absorbance of functionalized waveguides
- Planning of future work







PbS/CdS multiplie dot-in-rods



- Successive cation exchange steps transform original CdS rod into a PbS/CdS multiple dot-in-rod
- Passivation by CdS enhances PLQY to 45-55%

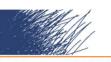
Justo et al., J. Am. Chem. Soc. 2012, 134, 5484-5487





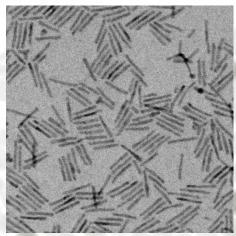


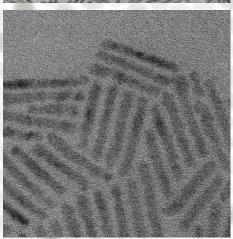


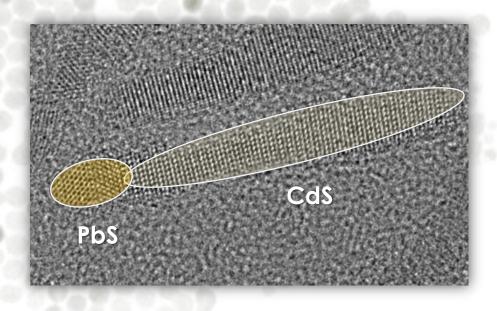


PbS/CdS dot-in-rods

PbS/CdS dot-in-rods





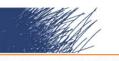






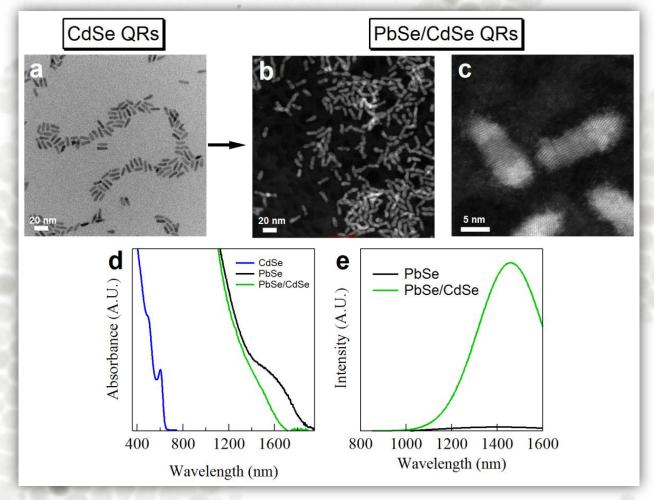






PbSe/CdSe rods

Similar synthesis as PbS/CdS dot-in-rods





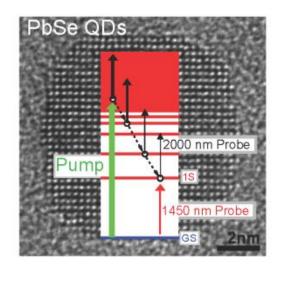


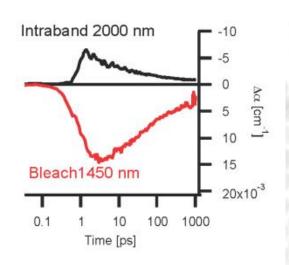






Intraband absorption





- Potential for switching
- Setback for gain (raises threshold)

De Geyter et al., accepted by ACS Nano





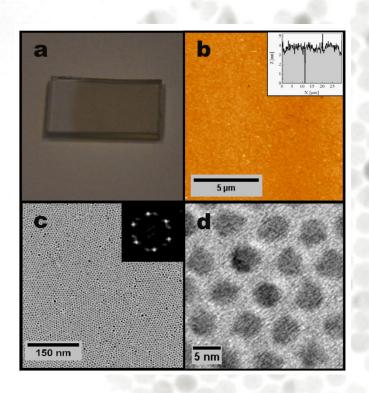




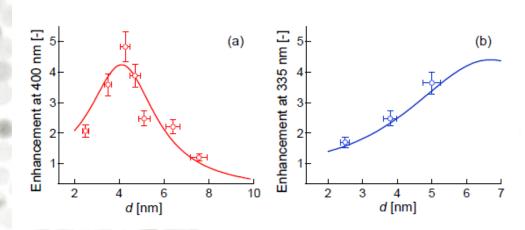


Absorption enhancement

Measurement of absorption cross section of QDs in close packed monolayer



$$E = \frac{\sigma_{film}}{\sigma_{sol}}$$



Geiregat et al., resubmitted to ACS Nano





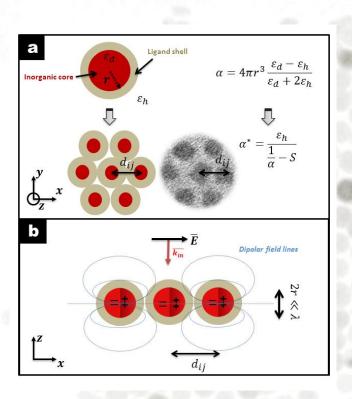




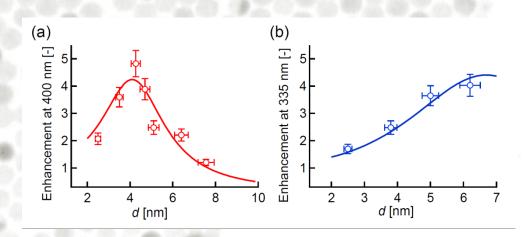


Absorption enhancement

Measurement of absorption cross section of QDs in close packed monolayer



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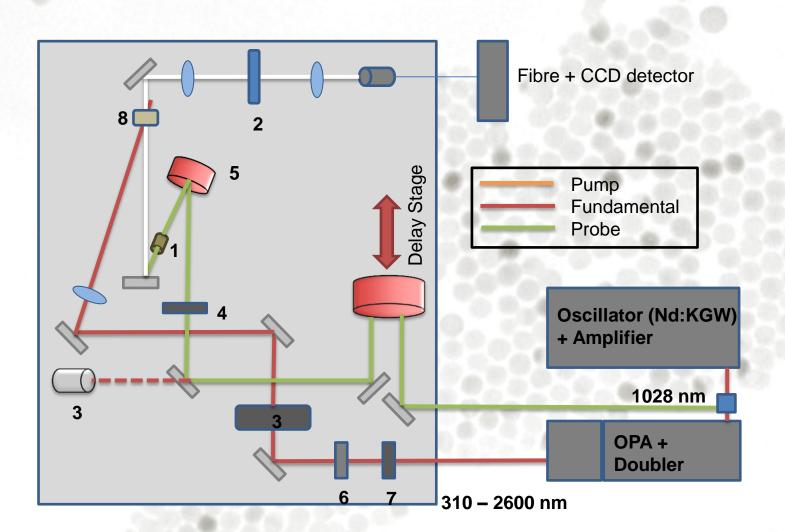
Geiregat et al., under review at ACS Nano









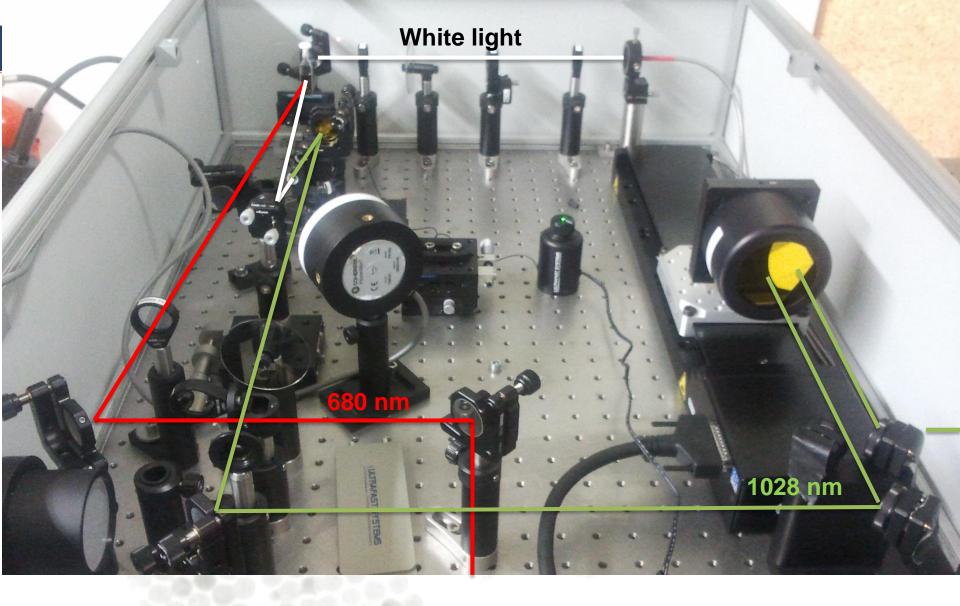












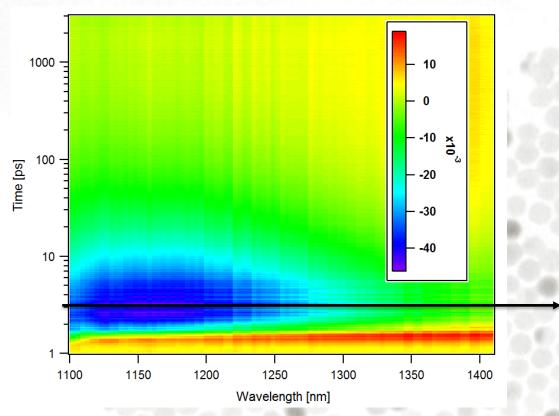
White light (up to 1600 nm) is created in sapphire crystal through 1028 nm pumping (fundamental of laser oscillator Nd:KGW).





PbS rods 4 x 12.8 nm

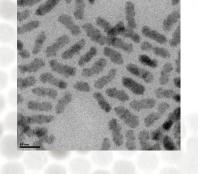
Analysis around Band Gap

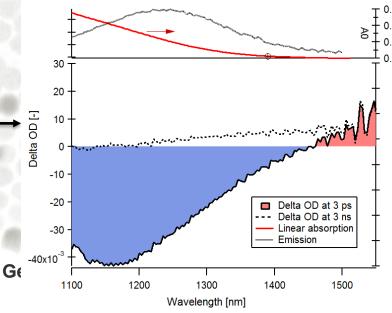


White light TA spectrum (now reliable up to 1600):

- Bleach band
- PA band





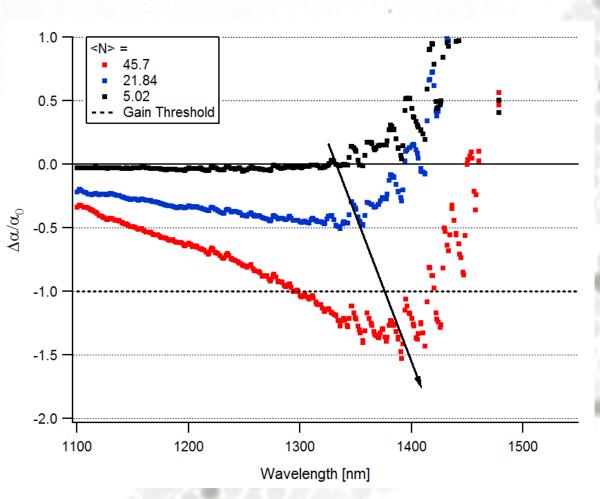








Pump dependent spectra



Bleach maximum redshifts due to increased multi-exciton shifts

At gain transition (ca. 1400 nm) you evolve from an absorbing transition at low fluence to a full bleach at high fluence.

How?

Competition between PA and gain buildup with different dependence on carrier density?





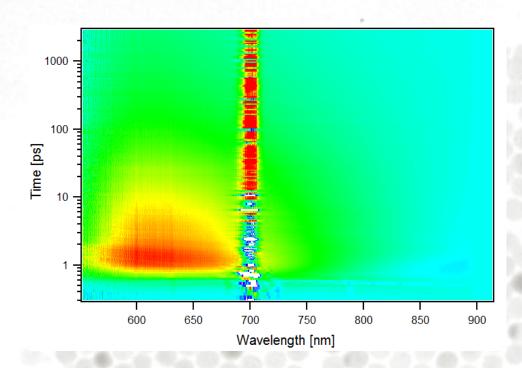






PbS rods 4 x 12.8 nm

Analysis in the visible



- Pronounced PA absorbance also for supra bandgap light
- Measurements also done on PbS dots analysis ongoing



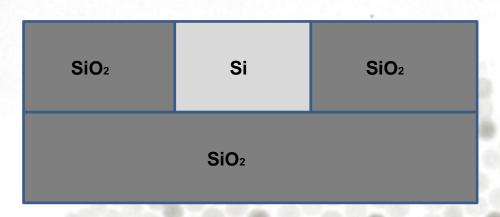


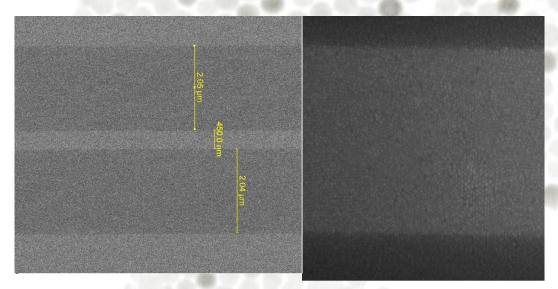




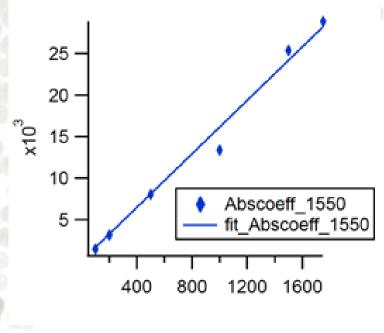


Absorbance of QD functionalized waveguide





$$loss, wg, L = \alpha \Delta L = \frac{\Delta P, dB}{10 \log(e)}$$



$$\Delta L_{um}$$

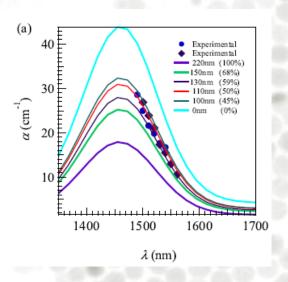


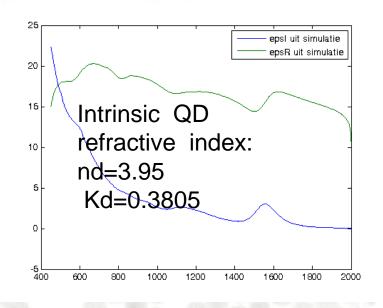


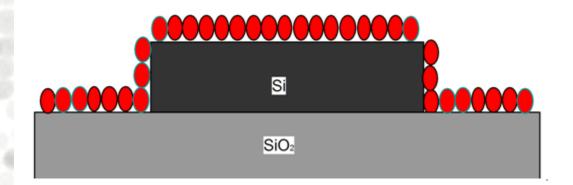




Non-planarized







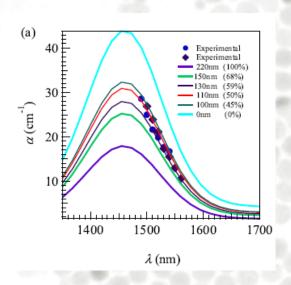








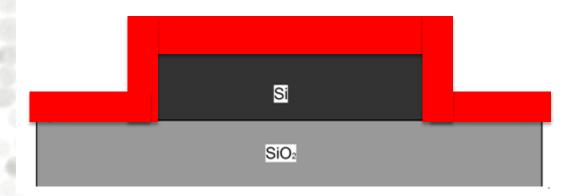
Non-planarized



Effective medium refractive refractive index (MG):

n=1.876

K = 0.034

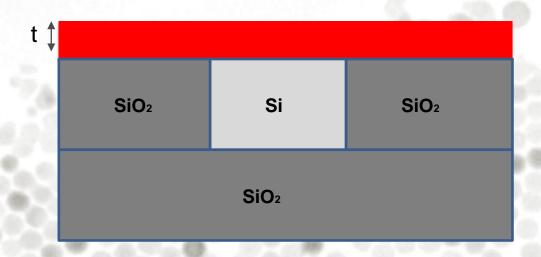


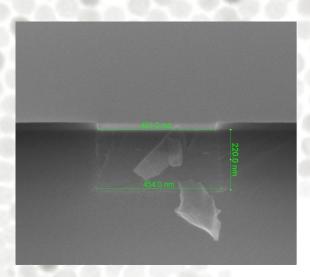


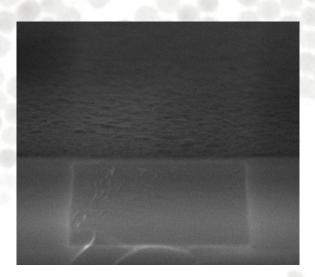










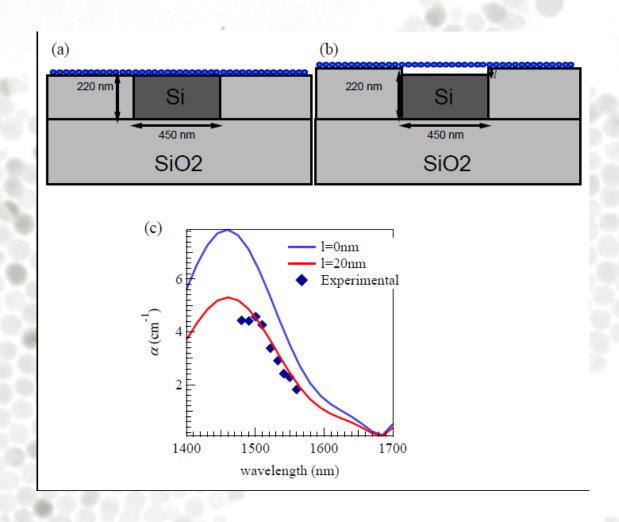










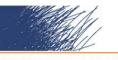












Future work

- **Materials syntesis**
 - HR-TEM analysis of PbSe/CdSe QDs
- Continuation of Transient Absorption spectroscopy
 - Benchmarking relative to PbS and PbS/CdS QDs
 - Analysis of PbS/CdS and PbSe/CdSe dot(s)-in-rod
- Sample exchange with Valencia
 - Discussion on report needed





